TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic
TC7SHU04FE

## INVERTER (Un-Buffer)

## Features

- Super high speed operation :tPD $=3.5 \mathrm{~ns}$ (typ.)

$$
@ \mathrm{~V}_{\mathrm{CC}}=5 \mathrm{~V}
$$

- Low power dissipation : ICC $=2 \mu \mathrm{~A}$ (Max.)

$$
\text { @ } \mathrm{Ta}=25^{\circ} \mathrm{C}
$$

- High noise immunity : VNIH $=\mathrm{V}_{\mathrm{NIH}}$

$$
=10 \% \mathrm{~V}_{\mathrm{CC}}(\mathrm{Min} .)
$$

- 5.5 V tolerant input.
- Wide operation voltage range : VCC (opr) $=2 \sim 5.5 \mathrm{~V}$


## Marking




Weight: 0.003 g (typ.)

Pin Assignment (top view)


Maximum Ratings $\left(\mathbf{T a}=25^{\circ} \mathrm{C}\right)$

| Characteristics | Symbol | Rating | Unit |
| :--- | :---: | :---: | :---: |
| Supply voltage range | $\mathrm{V}_{\text {CC }}$ | $-0.5 \sim 7$ | V |
| DC input voltage | $\mathrm{V}_{\text {IN }}$ | $-0.5 \sim 7$ | V |
| DC output voltage | $\mathrm{V}_{\text {OUT }}$ | $-0.5 \sim \mathrm{~V}_{\mathrm{CC}}+0.5$ | V |
| Input diode current | $\mathrm{I}_{\mathrm{IK}}$ | -20 | mA |
| Output diode current | $\mathrm{I}_{\mathrm{OK}}$ | $\pm 20$ | mA |
| DC output current | $\mathrm{I}_{\mathrm{OUT}}$ | $\pm 25$ | mA |
| DC $\mathrm{V}_{\text {CC }} /$ ground current | $\mathrm{I}_{\mathrm{CC}}$ | $\pm 50$ | mA |
| Power dissipation | $\mathrm{P}_{\mathrm{D}}$ | 150 | mW |
| Storage temperature | $\mathrm{T}_{\text {Stg }}$ | $-65 \sim 150$ | ${ }^{\circ} \mathrm{C}$ |

## Logic Diagram

IN A
$\square$
Truth Table


Recommended Operating Conditions

| Characteristics | Symbol | Rating | Unit |
| :--- | :---: | :---: | :---: |
| Supply voltage | $\mathrm{V}_{\mathrm{CC}}$ | $2 \sim 5.5$ | V |
| Input voltage | $\mathrm{V}_{\text {IN }}$ | $0 \sim 5.5$ | V |
| Output voltage | $\mathrm{V}_{\text {OUT }}$ | $0 \sim \mathrm{~V}_{\mathrm{CC}}$ | V |
| Operating temperature | $\mathrm{T}_{\text {Opr }}$ | $-40 \sim 85$ | ${ }^{\circ} \mathrm{C}$ |

## Electrical Characteristics

DC Characteristics

| Characteristics | Symbol | Test Circuit | Test Condition |  |  | $\mathrm{Ta}=25^{\circ} \mathrm{C}$ |  |  | $\mathrm{Ta}=-40 \sim 85^{\circ} \mathrm{C}$ |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  |  |  | $\mathrm{V}_{\mathrm{Cc}}(\mathrm{V})$ | Min | Typ. | Max | Min | Max |  |
| High-level input voltage | $\mathrm{V}_{\mathrm{IH}}$ | - | - |  | 2.0 | 1.7 | - | - | 1.7 | - | V |
|  |  |  |  |  | 3.0~5.5 | $\begin{aligned} & V_{C C} \\ & \times 0.8 \end{aligned}$ | - | - | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}} \\ & \times 0.8 \end{aligned}$ | - |  |
| Low-level input voltage | VIL | - | - |  | 2.0 | - | - | 0.3 | - | 0.3 | V |
|  |  |  |  |  | 3.0~5.5 | - | - | $\begin{aligned} & \mathrm{V}_{\mathrm{CC}} \\ & \times 0.2 \end{aligned}$ | - | $\begin{aligned} & V_{C c} \\ & \times 0.2 \end{aligned}$ |  |
| High-level output voltage | $\mathrm{V}_{\mathrm{OH}}$ | - | $\mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\text {IL }}$ | $\mathrm{IOH}=-50 \mu \mathrm{~A}$ | 2.0 | 1.8 | 2.0 | - | 1.8 | - | V |
|  |  |  |  |  | 3.0 | 2.7 | 3.0 | - | 2.7 | - |  |
|  |  |  |  |  | 4.5 | 4.0 | 4.5 | - | 4.0 | - |  |
|  |  |  | $\mathrm{V}_{\text {IN }}=\mathrm{GND}$ | $\mathrm{IOH}=-4 \mathrm{~mA}$ | 3.0 | 2.58 | - | - | 2.48 | - |  |
|  |  |  |  | $\mathrm{l}_{\mathrm{OH}}=-8 \mathrm{~mA}$ | 4.5 | 3.94 | - | - | 3.80 | - |  |
| Low-level output voltage | $\mathrm{V}_{\mathrm{OL}}$ | - | $\mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\text {IH }}$ | $\mathrm{l} \mathrm{OL}=50 \mu \mathrm{~A}$ | 2.0 | - | 0 | 0.2 | - | 0.2 | V |
|  |  |  |  |  | 3.0 | - | 0 | 0.3 | - | 0.3 |  |
|  |  |  |  |  | 4.5 | - | 0 | 0.5 | - | 0.5 |  |
|  |  |  | $\mathrm{V}_{\text {IN }}=\mathrm{V}_{\mathrm{CC}}$ | $\mathrm{IOL}=4 \mathrm{~mA}$ | 3.0 | - | - | 0.36 | - | 0.44 |  |
|  |  |  |  | $\mathrm{IOL}=8 \mathrm{~mA}$ | 4.5 | - | - | 0.36 | - | 0.44 |  |
| Input leakage current | IIN | - | $\mathrm{V}_{\text {IN }}=5.5 \mathrm{~V}$ or GND |  | 0~5.5 | - | - | $\pm 0.1$ | - | $\pm 1.0$ | $\mu \mathrm{A}$ |
| Quiescent supply current | ICC | - | $\mathrm{V}_{\mathrm{IN}}=\mathrm{V}_{\mathrm{CC}}$ or GND |  | 5.5 | - | - | 2.0 | - | 20.0 | $\mu \mathrm{A}$ |

AC Characteristics (input: $\mathbf{t}_{\mathbf{r}}=\mathbf{t}_{\mathbf{f}}=\mathbf{3} \mathbf{n s}$ )

| Characteristics | Symbol | Test Condition |  | $\mathrm{Ta}=25^{\circ} \mathrm{C}$ |  |  | $\mathrm{Ta}=-40 \sim 85^{\circ} \mathrm{C}$ |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\mathrm{V}_{\mathrm{Cc}}(\mathrm{V})$ | $\mathrm{C}_{\mathrm{L}}(\mathrm{pF})$ | Min | Typ. | Max | Min | Max |  |
| Propagation delay time | $\begin{aligned} & \text { tPLH } \\ & \text { tpHL }^{2} \end{aligned}$ | $3.3 \pm 0.3$ | 15 | - | 5.0 | 8.9 | 1.0 | 10.5 | ns |
|  |  |  | 50 | - | 7.5 | 11.4 | 1.0 | 13.0 |  |
|  |  | $5.0 \pm 0.5$ | 15 | - | 3.5 | 5.5 | 1.0 | 6.5 |  |
|  |  |  | 50 | - | 5.0 | 7.0 | 1.0 | 8.0 |  |
| Input capacitance | $\mathrm{C}_{\text {IN }}$ |  |  | - | 5 | 10 | - | 10 | pF |
| Power dissipation capacitance | CPD | (Note) |  | - | 6 | - | - | - | pF |

Note: $C_{P D}$ is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation.
$\operatorname{ICC}(\mathrm{opr})=$ CPD $\cdot \mathrm{VCC}_{C C} \cdot f \mathrm{fIN}+\mathrm{ICC}$

## Package Dimensions

SON5-P-0.50 Unit : mm


Weight: 0.003 g (typ.)

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